



Dual Channel Precision Adjustable Current-Limited Power Switches

 Check for Samples: [TPS2560A](#), [TPS2561A](#)

FEATURES

- Two separate current limiting channels
- Meets USB Current-Limiting Requirements
- Adjustable Current Limit, 250 mA–2.8 A (typ)
- Accurate 2.1A Min / 2.5A Max Setting (Including Resistor)
- Fast Overcurrent Response - 3.5- μ s (typ)
- Two 44-m Ω High-Side MOSFETs
- Operating Range: 2.5 V to 6.5 V
- 2- μ A Maximum Standby Supply Current
- Built-in Soft-Start
- 15 kV / 8 kV System-Level ESD Capable
- UL Listed – File No. E169910
- CB & Nemko Certified

APPLICATIONS

- USB Ports/Hubs
- Digital TV
- Set-Top Boxes
- VOIP Phones

DESCRIPTION

The TPS2560A and TPS2561A are dual-channel power-distribution switches intended for applications where precision current limiting is required or heavy capacitive loads and short circuits are encountered. These devices offer a programmable current-limit threshold between 250 mA and 2.8 A (typ) per channel via an external resistor. The power-switch rise and fall times are controlled to minimize current surges during turn on/off.

Each channel of the TPS2560A/61A devices limits the output current to a safe level by switching into a constant-current mode when the output load exceeds the current-limit threshold. The FAULTx logic output for each channel independently asserts low during overcurrent and over temperature conditions.

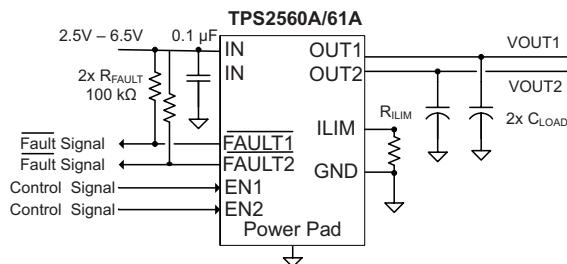
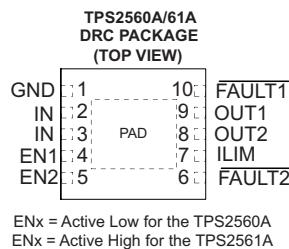


Figure 1. Typical Application as USB Power Switch

GENERAL SWITCH CATALOG						
33 m Ω , single	80 m Ω , single	80 m Ω , dual	80 m Ω , dual	80 m Ω , triple	80 m Ω , quad	80 m Ω , quad
TPS201xA 0.2A - 2A	TPS2014 600 mA	TPS2042B 500 mA	TPS2080 500 mA	TPS2043B 500 mA	TPS2044B 500 mA	TPS2085 500 mA
TPS202x 0.2A - 2A	TPS2015 1 A	TPS2041B 500 mA	TPS2045B 250 mA	TPS2081 500 mA	TPS2045B 250 mA	TPS2086 500 mA
TPS203x 0.2A - 2A	TPS2016 100 mA	TPS2044B 250 mA	TPS2082 500 mA	TPS2046B 250 mA	TPS2046B 250 mA	TPS2087 500 mA
	TPS2024B 250 mA	TPS2045B 1 A	TPS2083B 250 mA	TPS2047B 250 mA	TPS2047B 250 mA	TPS2088 500 mA
	TPS2024A 250 mA	TPS2046B 1 A	TPS2084B 250 mA	TPS2048B 250 mA	TPS2048B 250 mA	TPS2089 250 mA
	TPS20261 1 A	TPS2060 1.5 A	TPS2085B 250 mA	TPS2049B 250 mA	TPS2049B 250 mA	TPS2090 250 mA
	TPS20265 1 A	TPS2066 1 A	TPS2090 250 mA	TPS2050B 250 mA	TPS2050B 250 mA	TPS2091 250 mA
	TPS20268 1.5 A	TPS2064 1.5 A	TPS2092 250 mA	TPS2054B 250 mA	TPS2054B 250 mA	TPS2092 250 mA
	TPS20269 1.5 A			TPS2057B 250 mA	TPS2057B 250 mA	TPS2093 250 mA



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

AVAILABLE OPTIONS AND ORDERING INFORMATION

DEVICE ⁽¹⁾	AMBIENT TEMPERATURE ⁽²⁾	ENABLE	SON ⁽³⁾ (DRC)	MARKING	RECOMMENDED MAXIMUM CONTINUOUS LOAD CURRENT PER CHANNEL
TPS2560A	–40°C to 85°C	Active low	TPS2560ADRC	2560A	2.5 A
TPS2561A		Active high	TPS2561ADRC	2561A	

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.
- (2) Maximum ambient temperature is a function of device junction temperature and system level considerations, such as power dissipation and board layout. See *dissipation rating table* and *recommended operating conditions* for specific information related to these devices.
- (3) Add an R suffix to the device type for tape and reel.

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range unless otherwise noted^{(1) (2)}

		VALUE	UNIT
Voltage range on IN, OUTx, ENx or ENx, ILIM, FAULTx		–0.3 to 7	V
Voltage range from IN to OUTx		–7 to 7	V
Continuous output current		Internally Limited	
Continuous total power dissipation		See the Dissipation Rating Table	
Continuous FAULTx sink current		25	mA
ILIM source current		Internally Limited	mA
ESD	HBM	2	kV
	CDM	500	V
ESD – system level (contact/air) ⁽³⁾		8/15	kV
T _J	Maximum junction temperature	–40 to OTSD2 ⁽⁴⁾	°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Voltages are referenced to GND unless otherwise noted.
- (3) Surges per EN61000-4-2, 1999 applied between USB and output ground of the TPS2560AEVM (HPA424) evaluation module (documentation available on the Web.) These were the test level, not the failure threshold.
- (4) Ambient over temperature shutdown threshold

DISSIPATION RATING TABLE

BOARD	PACKAGE	THERMAL RESISTANCE ⁽¹⁾ θ _{JA}	THERMAL RESISTANCE θ _{JC}	T _A ≤ 25°C POWER RATING
High-K ⁽²⁾	DRC	41.6 °C/W	10.7 °C/W	2403 mW

- (1) Mounting per the *PowerPAD™ Thermally Enhanced Package* application report (SLMA002)
- (2) The JEDEC high-K (2s2p) board used to derive this data was a 3in × 3in, multilayer board with 1-ounce internal power and ground planes and 2-ounce copper traces on top and bottom of the board.

RECOMMENDED OPERATING CONDITIONS

			MIN	MAX	UNIT
V_{IN}	Input voltage, IN		2.5	6.5	V
V_{ENx}	Enable voltage	TPS2560A	0	6.5	V
V_{ENx}		TPS2561A	0	6.5	
V_{IH}	High-level input voltage on ENx or \overline{ENx}		1.1		V
V_{IL}	Low-level input voltage on ENx or \overline{ENx}			0.66	
I_{OUTx}	Continuous output current per channel, OUTx		0	2.5	A
	Continuous FAULTx sink current		0	10	mA
T_J	Operating virtual junction temperature		-40	125	°C
R_{ILIM}	Recommended resistor limit range		20	187	kΩ

ELECTRICAL CHARACTERISTICS

over recommended operating conditions, $V_{ENx} = 0$ V, or $V_{ENx} = V_{IN}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS ⁽¹⁾		MIN	TYP	MAX	UNIT
POWER SWITCH						
$r_{DS(on)}$	Static drain-source on-state resistance per channel, IN to OUTx	$T_J = 25$ °C		44	50	mΩ
		-40 °C $\leq T_J \leq 125$ °C		70		
t_r	Rise time, output	$V_{IN} = 6.5$ V	$C_{Lx} = 1 \mu F$, $R_{Lx} = 100 \Omega$, (see Figure 2)	2	3	4
		$V_{IN} = 2.5$ V		1	2	3
t_f	Fall time, output	$V_{IN} = 6.5$ V		0.6	0.8	1.0
		$V_{IN} = 2.5$ V		0.4	0.6	0.8
ENABLE INPUT EN OR \overline{EN}						
I_{EN}	Enable pin turn on/off threshold			0.66	1.1	V
	Hysteresis			55 ⁽²⁾		mV
t_{on}	Input current	$V_{ENx} = 0$ V or 6.5 V, $V_{ENx} = 0$ V or 6.5 V		-0.5	0.5	μA
t_{off}	Turnon time	$C_{Lx} = 1 \mu F$, $R_{Lx} = 100 \Omega$, (see Figure 2)			9	ms
					6	ms
CURRENT LIMIT						
I_{os}	Current-limit (see Figure 4)	OUTx connected to GND	$R_{ILIM} = 24.3$ kΩ±1%	2100	2300	2500
		OUT1 and OUT2 connected to GND	$R_{ILIM} = 47.5$ kΩ±1%	2100	2300	2500
t_{ios}	Response time to short circuit	$V_{IN} = 5.0$ V (see Figure 3)		3.5 ⁽²⁾		μs

- (1) Pulse-testing techniques maintain junction temperature close to ambient temperature; thermal effects must be taken into account separately.
- (2) These parameters are provided for reference only, and do not constitute part of TI's published specifications for purposes of TI's product warranty.

ELECTRICAL CHARACTERISTICS (continued)over recommended operating conditions, $V_{ENx} = 0$ V, or $V_{ENx} = V_{IN}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS ⁽¹⁾	MIN	TYP	MAX	UNIT
SUPPLY CURRENT					
I_{IN_off}	Supply current, low-level output $V_{IN} = 6.5$ V, No load on OUTx, $V_{ENx} = 6.5$ V or $V_{ENx} = 0$ V	0.1	2.0	μA	
I_{IN_on}	$V_{IN} = 6.5$ V, No load on OUT	$R_{ILIM} = 20$ kΩ	100	125	μA
		$R_{ILIM} = 100$ kΩ	85	110	μA
I_{REV}	Reverse leakage current $V_{OUTx} = 6.5$ V, $V_{IN} = 0$ V	$T_J = 25^\circ\text{C}$	0.01	1.0	μA
UNDERVOLTAGE LOCKOUT					
UVLO	Low-level input voltage, IN V_{IN} rising	2.35	2.45		V
	Hysteresis, IN $T_J = 25^\circ\text{C}$	35			mV
FAULTx FLAG					
V_{OL}	$I_{FAULTx} = 1$ mA	180			mV
Off-state leakage	$V_{FAULTx} = 6.5$ V	1			μA
FAULTx deglitch	FAULTx assertion or de-assertion due to overcurrent condition	6	9	13	ms
THERMAL SHUTDOWN					
OTSD2	Thermal shutdown threshold	155			°C
OTSD	Thermal shutdown threshold in current-limit	135			°C
	Hysteresis	20 ⁽³⁾			°C

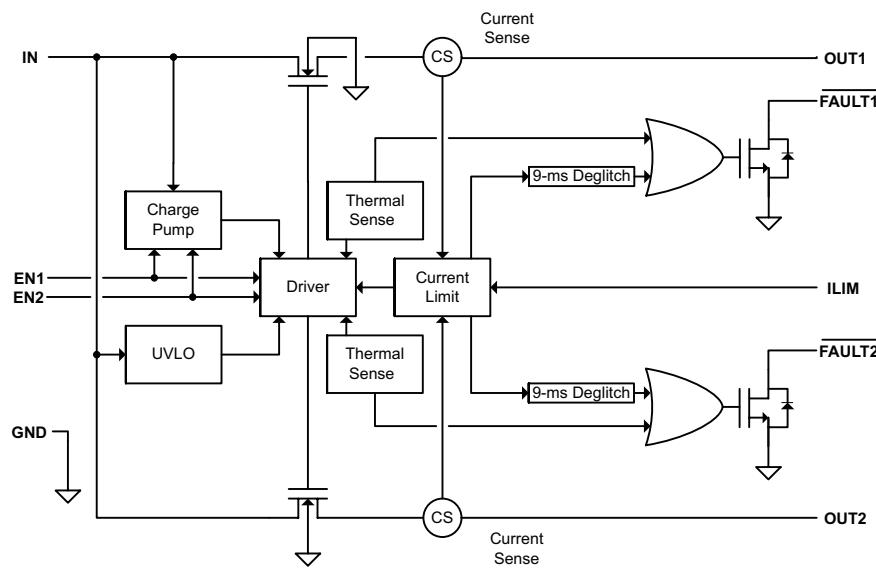
(3) These parameters are provided for reference only, and do not constitute part of TI's published specifications for purposes of TI's product warranty.

DEVICE INFORMATION

Pin Functions

PIN			I/O	DESCRIPTION
NAME	TPS2560A	TPS2561A		
EN1	4	-	I	Enable input, logic low turns on channel one power switch
EN1	-	4	I	Enable input, logic high turns on channel one power switch
EN2	5	-	I	Enable input, logic low turns on channel two power switch
EN2	-	5	I	Enable input, logic high turns on channel two power switch
GND	1	1		Ground connection; connect externally to PowerPAD
IN	2, 3	2, 3	I	Input voltage; connect a 0.1 μ F or greater ceramic capacitor from IN to GND as close to the IC as possible.
FAULT1	10	10	O	Active-low open-drain output, asserted during overcurrent or overtemperature condition on channel one.
FAULT2	6	6	O	Active-low open-drain output, asserted during overcurrent or overtemperature condition on channel two
OUT1	9	9	O	Power-switch output for channel one
OUT2	8	8	O	Power-switch output for channel two
ILIM	7	7	O	External resistor used to set current-limit threshold; recommended $20 \text{ k}\Omega \leq R_{\text{ILIM}} \leq 187 \text{ k}\Omega$.
PowerPAD TM	PAD	PAD		Internally connected to GND; used to heat-sink the part to the circuit board traces. Connect PowerPAD to GND pin externally.

FUNCTIONAL BLOCK DIAGRAM



PARAMETER MEASUREMENT INFORMATION

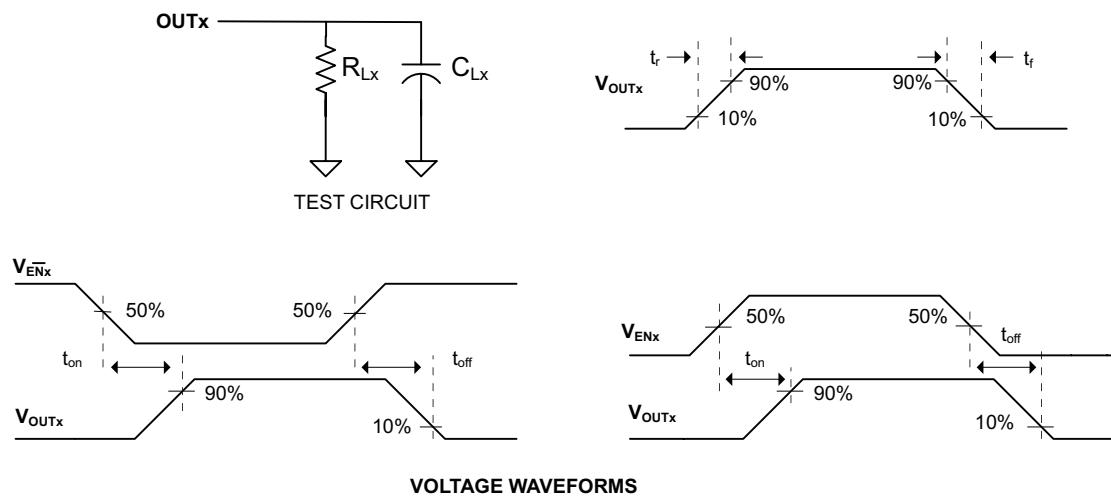


Figure 2. Test Circuit and Voltage Waveforms

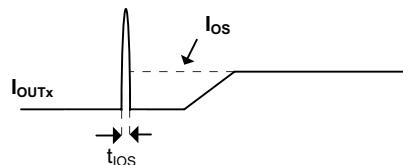


Figure 3. Response Time to Short Circuit Waveform

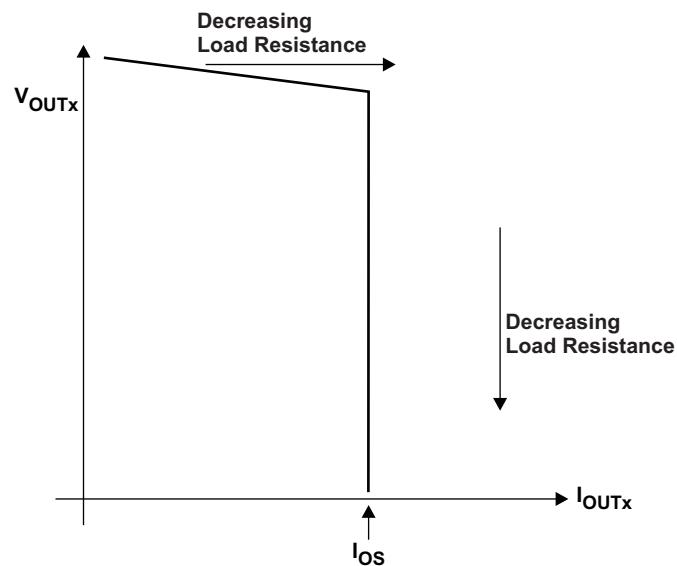


Figure 4. Output Voltage vs. Current-Limit Threshold

TYPICAL CHARACTERISTICS

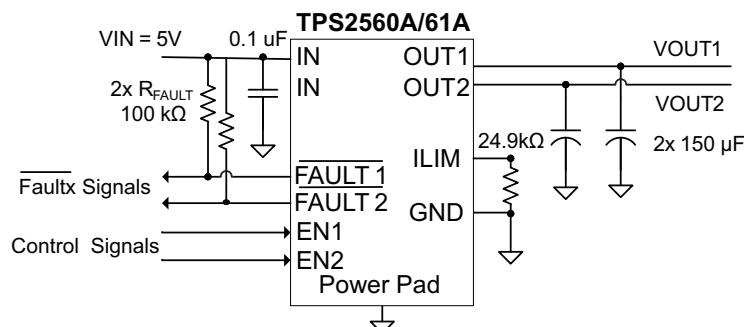


Figure 5. Typical Characteristics Reference Schematic

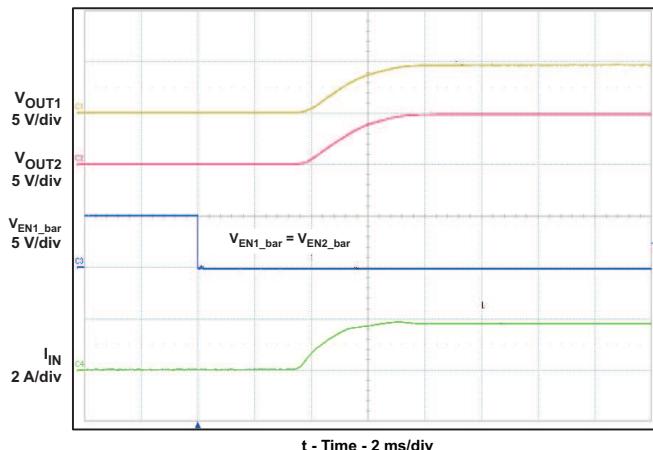


Figure 6. Turn-on Delay and Rise Time

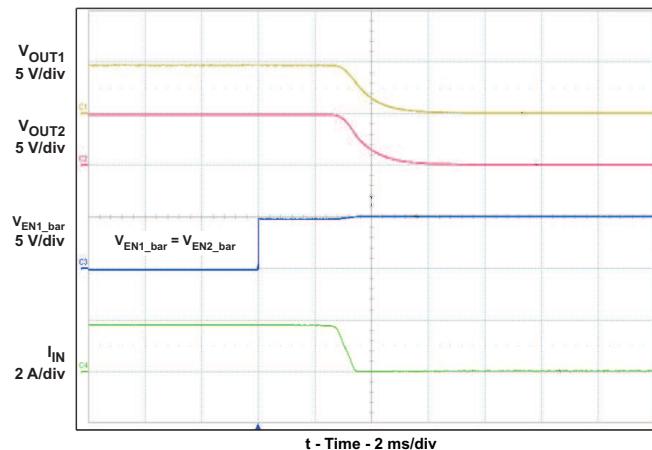


Figure 7. Turn-off Delay and Fall Time

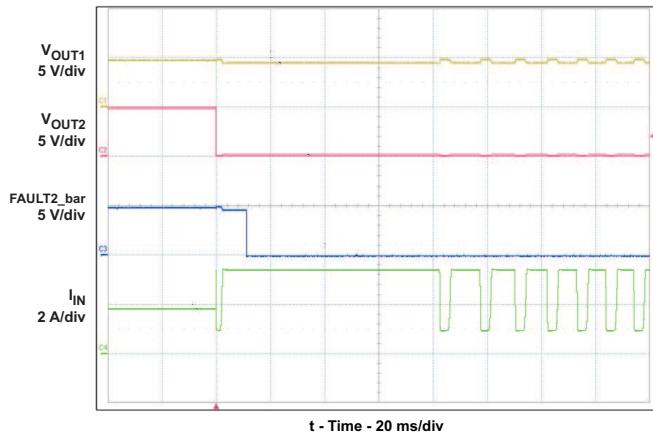


Figure 8. Full-Load to Short-Circuit Transient Response

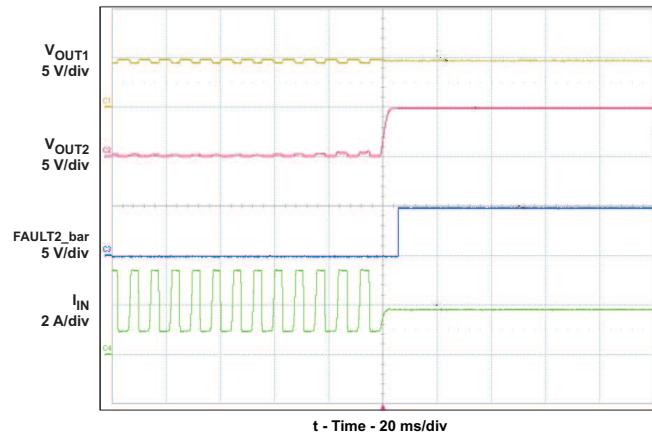


Figure 9. Short-Circuit to Full-Load Recovery Response

TYPICAL CHARACTERISTICS (continued)

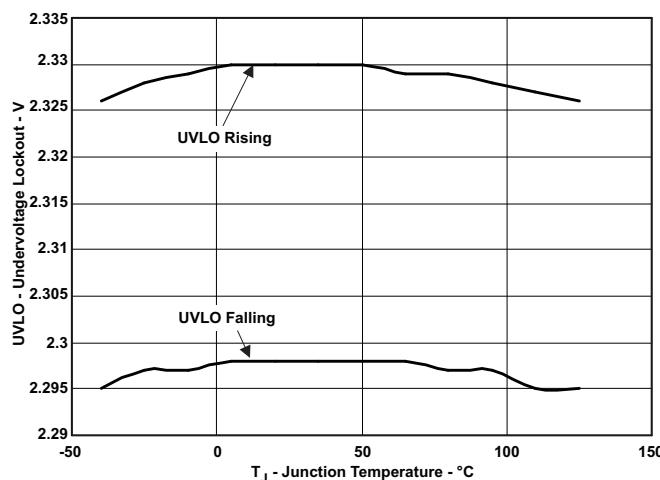


Figure 10. UVLO – Undervoltage Lockout – V

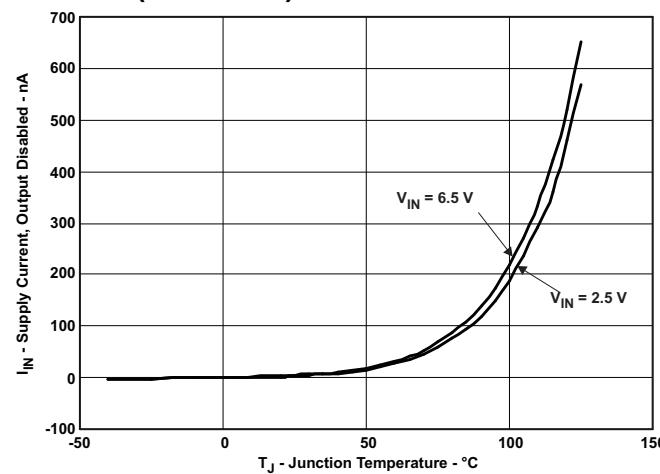


Figure 11. I_IN – Supply Current, Output Disabled – nA

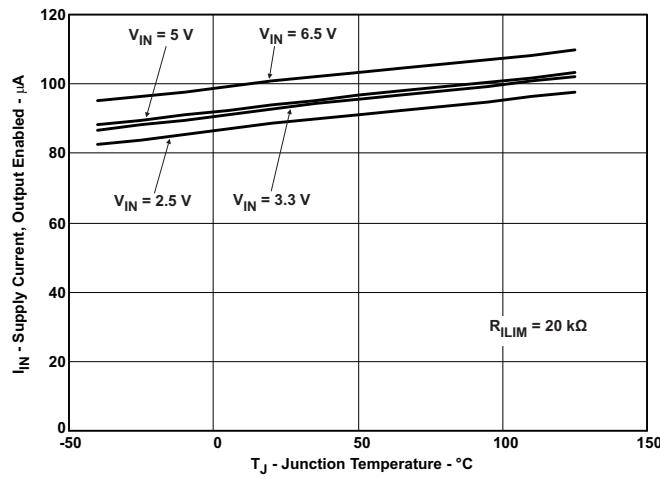


Figure 12. I_IN – Supply Current, Output Enabled – μA

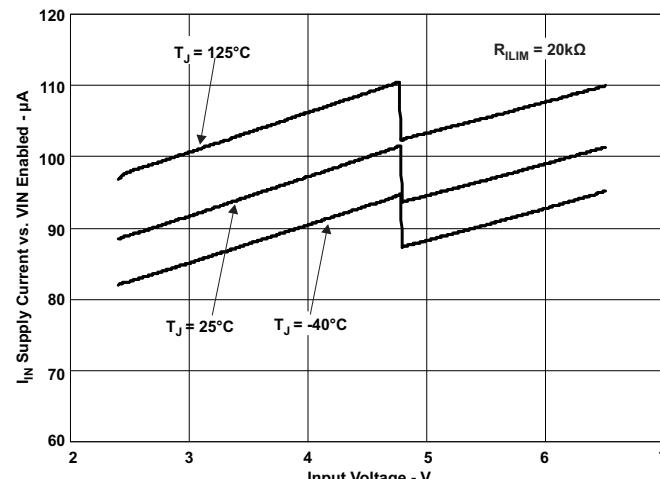


Figure 13. I_IN – Supply Current, Output Enabled – μA

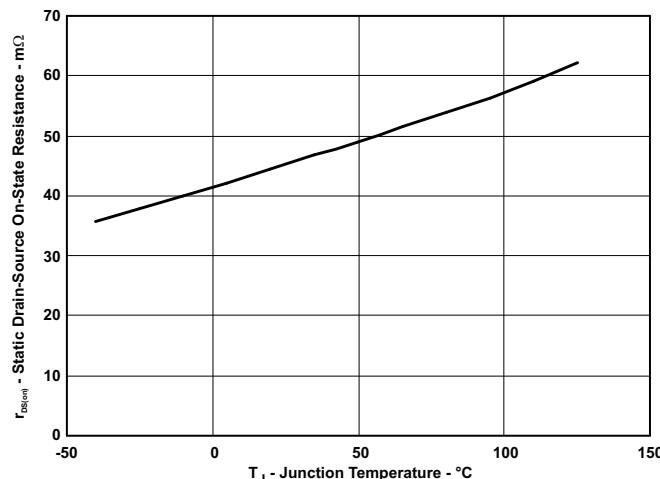


Figure 14. MOSFET $r_{DS(on)}$ Vs. Junction Temperature

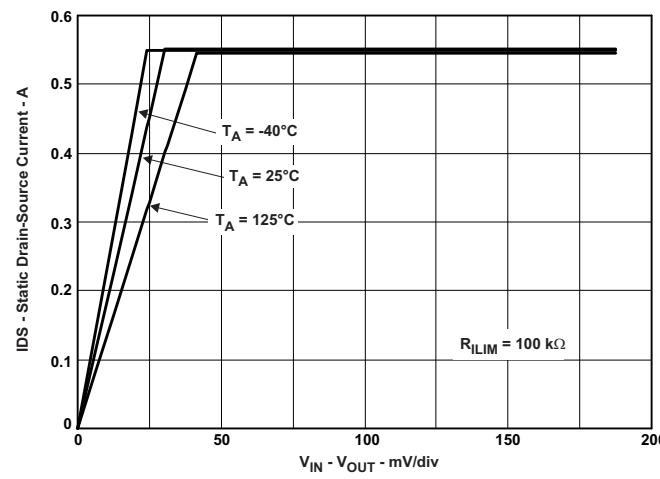


Figure 15. Switch Current Vs. Drain-Source Voltage Across Switch

TYPICAL CHARACTERISTICS (continued)

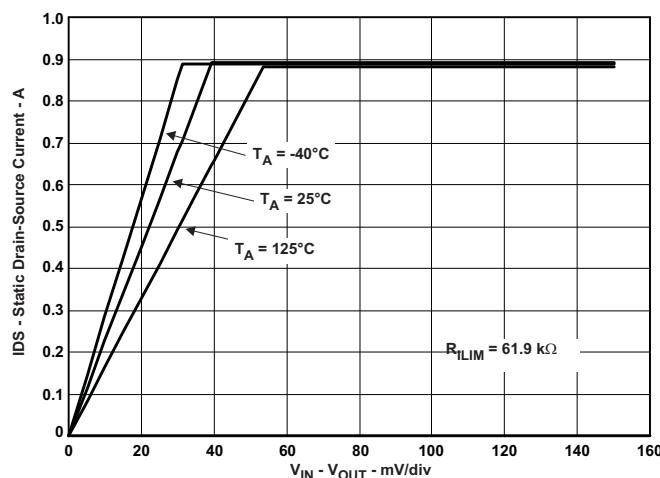


Figure 16. Switch Current Vs. Drain-Source Voltage Across Switch

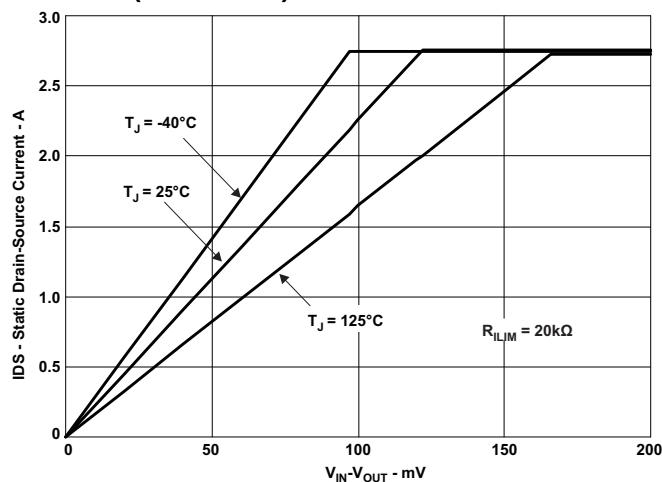


Figure 17. Switch Current vs. Drain-Source Voltage Across Switch

DETAILED DESCRIPTION

OVERVIEW

The TPS2560A/61A is a dual-channel, current-limited power-distribution switch using N-channel MOSFETs for applications where short circuits or heavy capacitive loads will be encountered. This device allows the user to program the current-limit threshold between 250 mA and 2.8 A (typ) per channel via an external resistor. This device incorporates an internal charge pump and gate drive circuitry necessary to drive the N-channel MOSFETs. The charge pump supplies power to the driver circuit for each channel and provides the necessary voltage to pull the gate of the MOSFET above the source. The charge pump operates from input voltages as low as 2.5 V and requires little supply current. The driver controls the gate voltage of the power switch. The driver incorporates circuitry that controls the rise and fall times of the output voltage to limit large current and voltage surges and provides built-in soft-start functionality. Each channel of the TPS2560A/61A limits the output current to the programmed current-limit threshold I_{OS} during an overcurrent or short-circuit event by reducing the charge pump voltage driving the N-channel MOSFET and operating it in the linear range of operation. The result of limiting the output current to I_{OS} reduces the output voltage at OUTx because the N-channel MOSFET is no longer fully enhanced.

OVERCURRENT CONDITIONS

The TPS2560A/61A responds to overcurrent conditions by limiting the output current per channel to I_{OS} . When an overcurrent condition is detected, the device maintains a constant output current and reduces the output voltage accordingly. Two possible overload conditions can occur.

The first condition is when a short circuit or partial short circuit is present when the device is powered-up or enabled. The output voltage is held near zero potential with respect to ground and the TPS2560A/61A ramps the output current to I_{OS} . The TPS2560A/61A devices will limit the current to I_{OS} until the overload condition is removed or the device begins to thermal cycle.

The second condition is when a short circuit, partial short circuit, or transient overload occurs while the device is enabled and powered on. The device responds to the overcurrent condition within time t_{IOS} (see [Figure 3](#)). The current-sense amplifier is overdriven during this time and momentarily disables the internal current-limit MOSFET. The current-sense amplifier recovers and ramps the output current to I_{OS} . Similar to the previous case, the TPS2560A/61A will limit the current to I_{OS} until the overload condition is removed or the device begins to thermal cycle.

The TPS2560A/61A thermal cycles if an overload condition is present long enough to activate thermal limiting in any of the above cases. The device turns off when the junction temperature exceeds 135°C (min) while in current limit. The device remains off until the junction temperature cools 20°C (typ) and then restarts. The TPS2560A/61A cycles on/off until the overload is removed (see [Figure 9](#)).

FAULTx RESPONSE

The FAULTx open-drain outputs are asserted (active low) on an individual channel during an overcurrent or overtemperature condition. The TPS2560A/61A asserts the FAULTx signal until the fault condition is removed and the device resumes normal operation on that channel. The TPS2560A/61A is designed to eliminate false FAULTx reporting by using an internal delay "deglitch" circuit (9-ms typ) for overcurrent conditions without the need for external circuitry. This ensures that FAULTx is not accidentally asserted due to normal operation such as starting into a heavy capacitive load. The deglitch circuitry delays entering and leaving current-limited induced fault conditions. The FAULTx signal is not deglitched when the MOSFET is disabled due to an overtemperature condition but is deglitched after the device has cooled and begins to turn on. This unidirectional deglitch prevents FAULTx oscillation during an overtemperature event.

UNDERVOLTAGE LOCKOUT (UVLO)

The undervoltage lockout (UVLO) circuit disables the power switch until the input voltage reaches the UVLO turn-on threshold. Built-in hysteresis prevents unwanted on/off cycling due to input voltage droop during turn on.

ENABLE (ENx OR ENx)

The logic enables control the power switches and device supply current. The supply current is reduced to less than 2- μ A when a logic high is present on ENx or when a logic low is present on ENx. A logic low input on ENx or a logic high input on ENx enables the driver, control circuits, and power switches. The enable inputs are compatible with both TTL and CMOS logic levels.

THERMAL SENSE

The TPS2560A/61A self protects by using two independent thermal sensing circuits that monitor the operating temperature of the power switch and disable operation if the temperature exceeds recommended operating conditions. Each channel of the TPS2560A/61A operates in constant-current mode during an overcurrent conditions, which increases the voltage drop across the power switch. The power dissipation in the package is proportional to the voltage drop across the power switch, which increases the junction temperature during an overcurrent condition. The first thermal sensor (OTSD) turns off the individual power switch channel when the die temperature exceeds 135°C (min) and the channel is in current limit. Hysteresis is built into the thermal sensor, and the switch turns on after the device has cooled approximately 20°C.

The TPS2560A/61A also has a second ambient thermal sensor (OTSD2). The ambient thermal sensor turns off both power switch channels when the die temperature exceeds 155°C (min) regardless of whether the power switch channels are in current limit and will turn on the power switches after the device has cooled approximately 20°C. The TPS2560A/61A continues to cycle off and on until the fault is removed.

APPLICATION INFORMATION

INPUT AND OUTPUT CAPACITANCE

Input and output capacitance improves the performance of the device; the actual capacitance should be optimized for the particular application. For all applications, a $0.1\mu\text{F}$ or greater ceramic bypass capacitor between IN and GND is recommended as close to the device as possible for local noise decoupling. This precaution reduces ringing on the input due to power-supply transients. Additional input capacitance may be needed on the input to reduce voltage overshoot from exceeding the absolute maximum voltage of the device during heavy transient conditions. This is especially important during bench testing when long, inductive cables are used to connect the evaluation board to the bench power supply.

Output capacitance is not required, but placing a high-value electrolytic capacitor on the output pin is recommended when large transient currents are expected on the output.

PROGRAMMING THE CURRENT-LIMIT THRESHOLD

The overcurrent threshold is user programmable via an external resistor, R_{ILIM} . R_{ILIM} sets the current-limit threshold for both channels. The TPS2560A/61A use an internal regulation loop to provide a regulated voltage on the ILIM pin. The current-limit threshold is proportional to the current sourced out of ILIM. The recommended 1% resistor range for R_{ILIM} is $20\text{ k}\Omega \leq R_{ILIM} \leq 187\text{ k}\Omega$ to ensure stability of the internal regulation loop. Many applications require that the minimum current limit is above a certain current level or that the maximum current limit is below a certain current level, so it is important to consider the tolerance of the overcurrent threshold when selecting a value for R_{ILIM} . The following equations calculates the resulting overcurrent threshold for a given external resistor value (R_{ILIM}). The traces routing the R_{ILIM} resistor to the TPS2560A/61A should be as short as possible to reduce parasitic effects on the current-limit accuracy.

$$\begin{aligned} I_{OSmax}(\text{mA}) &= \frac{52850\text{V}}{R_{ILIM}^{0.957}\text{k}\Omega} \\ I_{OSnom}(\text{mA}) &= \frac{56000\text{V}}{R_{ILIM}\text{k}\Omega} \\ I_{OSmin}(\text{mA}) &= \frac{61200\text{V}}{R_{ILIM}^{1.056}\text{k}\Omega} \end{aligned} \quad (1)$$

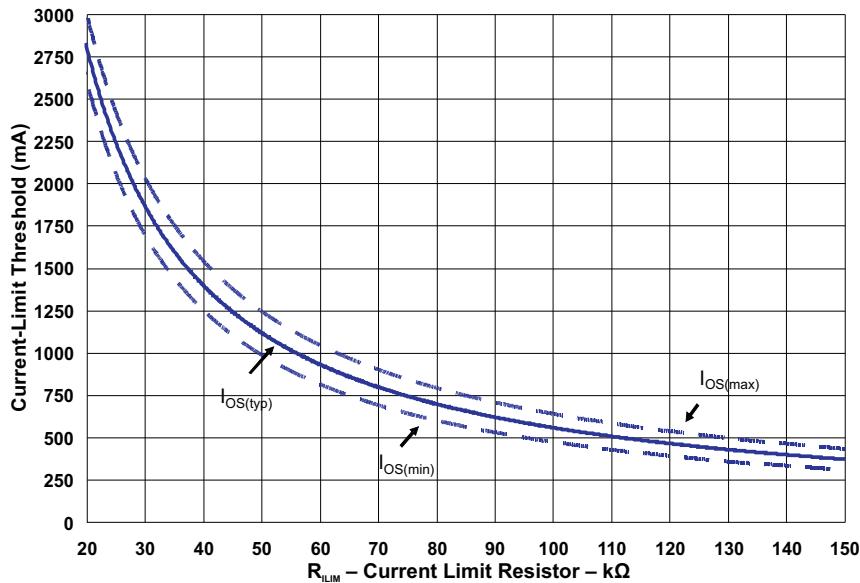


Figure 18. Current-Limit Threshold vs. R_{ILIM}

APPLICATION 1: DESIGNING ABOVE A MINIMUM CURRENT LIMIT

Some applications require that current limiting cannot occur below a certain threshold. For this example, assume that 2 A must be delivered to the load so that the minimum desired current-limit threshold is 2000 mA. Use the I_{OS} equations and [Figure 18](#) to select R_{ILIM} .

$$\begin{aligned}
 I_{OSmin}(\text{mA}) &= 2000 \text{mA} \\
 I_{OSmin}(\text{mA}) &= \frac{61200V}{R_{ILIM}^{1.056}\text{k}\Omega} \\
 R_{ILIM}(\text{k}\Omega) &= \left(\frac{61200V}{I_{OSmin}\text{mA}} \right)^{\frac{1}{1.056}} \\
 R_{ILIM}(\text{k}\Omega) &= 25.52\text{k}\Omega
 \end{aligned} \tag{2}$$

Select the closest 1% resistor less than the calculated value: $R_{ILIM} = 25.5$ kΩ. This sets the minimum current-limit threshold at 2 A. Use the I_{OS} equations, [Figure 18](#), and the previously calculated value for R_{ILIM} to calculate the maximum resulting current-limit threshold.

$$\begin{aligned}
 R_{ILIM}(\text{k}\Omega) &= 25.5\text{k}\Omega \\
 I_{OSmax}(\text{mA}) &= \frac{52850V}{R_{ILIM}^{0.957}\text{k}\Omega} \\
 I_{OSmax}(\text{mA}) &= \frac{52850V}{25.5^{0.957}\text{k}\Omega} \\
 I_{OSmax}(\text{mA}) &= 2382\text{mA}
 \end{aligned} \tag{3}$$

The resulting maximum current-limit threshold is 2382 mA with a 25.5 kΩ resistor.

APPLICATION 2: DESIGNING BELOW A MAXIMUM CURRENT LIMIT

Some applications require that current limiting must occur below a certain threshold. For this example, assume that the desired upper current-limit threshold must be below 1000 mA to protect an up-stream power supply. Use the I_{OS} equations and [Figure 18](#) to select R_{ILIM} .

$$\begin{aligned}
 I_{OSmax}(\text{mA}) &= 1000\text{mA} \\
 I_{OSmax}(\text{mA}) &= \frac{52850V}{R_{ILIM}^{0.957}\text{k}\Omega} \\
 R_{ILIM}(\text{k}\Omega) &= \left(\frac{52850V}{I_{OSmax}\text{mA}} \right)^{\frac{1}{0.957}} \\
 R_{ILIM}(\text{k}\Omega) &= 63.16\text{k}\Omega
 \end{aligned} \tag{4}$$

Select the closest 1% resistor greater than the calculated value: $R_{ILIM} = 63.4$ kΩ. This sets the maximum current-limit threshold at 1000 mA. Use the I_{OS} equations, [Figure 18](#), and the previously calculated value for R_{ILIM} to calculate the minimum resulting current-limit threshold.

$$\begin{aligned}
 R_{ILIM}(\text{k}\Omega) &= 63.4\text{k}\Omega \\
 I_{OSmin}(\text{mA}) &= \frac{61200V}{R_{ILIM}^{1.056}\text{k}\Omega} \\
 I_{OSmin}(\text{mA}) &= \frac{61200V}{63.4^{1.056}\text{k}\Omega} \\
 I_{OSmin}(\text{mA}) &= 765\text{mA}
 \end{aligned} \tag{5}$$

The resulting minimum current-limit threshold is 765 mA with a 63.4 kΩ resistor.

ACCOUNTING FOR RESISTOR TOLERANCE

The previous sections described the selection of R_{ILIM} given certain application requirements and the importance of understanding the current-limit threshold tolerance. The analysis focused only on the TPS2560A/61A performance and assumed an exact resistor value. However, resistors sold in quantity are not exact and are bounded by an upper and lower tolerance centered around a nominal resistance. The additional R_{ILIM} resistance tolerance directly affects the current-limit threshold accuracy at a system level. The following table shows a process that accounts for worst-case resistor tolerance assuming 1% resistor values. Step one follows the selection process outlined in the application examples above. Step two determines the upper and lower resistance bounds of the selected resistor. Step three uses the upper and lower resistor bounds in the I_{OS} equations to calculate the threshold limits. It is important to use tighter tolerance resistors, e.g. 0.5% or 0.1%, when precision current limiting is desired.

Table 1. Common R_{ILIM} Resistor Selections

Desired Nominal Current Limit (mA)	Ideal Resistor (kΩ)	Closest 1% Resistor (kΩ)	Resistor Tolerance		IOS MIN (mA)	IOS Nom (mA)	IOS MAX (mA)
			1% low (kΩ)	1% high (kΩ)			
300	186.7	187	185.1	188.9	241.6	299.5	357.3
400	140.0	140	138.6	141.4	328.0	400.0	471.4
600	93.3	93.1	92.2	94.0	504.6	601.5	696.5
800	70.0	69.8	69.1	70.5	684.0	802.3	917.6
1000	56.0	56.2	55.6	56.8	859.9	996.4	1129.1
1200	46.7	46.4	45.9	46.9	1052.8	1206.9	1356.3
1400	40.0	40.2	39.8	40.6	1225.0	1393.0	1555.9
1600	35.0	34.8	34.5	35.1	1426.5	1609.2	1786.2
1800	31.1	30.9	30.6	31.2	1617.3	1812.3	2001.4
2000	28.0	28	27.7	28.3	1794.7	2000.0	2199.3
2200	25.5	25.5	25.2	25.8	1981.0	2196.1	2405.3
2400	23.3	23.2	23.0	23.4	2188.9	2413.8	2633.0
2600	21.5	21.5	21.3	21.7	2372.1	2604.7	2831.9
2800	20.0	20	19.8	20.2	2560.4	2800.0	3034.8

POWER DISSIPATION AND JUNCTION TEMPERATURE

The low on-resistance of the N-channel MOSFET allows small surface-mount packages to pass large currents. It is good design practice to estimate power dissipation and junction temperature. The below analysis gives an approximation for calculating junction temperature based on the power dissipation in the package. However, it is important to note that thermal analysis is strongly dependent on additional system level factors. Such factors include air flow, board layout, copper thickness and surface area, and proximity to other devices dissipating power. Good thermal design practice must include all system level factors in addition to individual component analysis.

Begin by determining the $r_{DS(on)}$ of the N-channel MOSFET relative to the input voltage and operating temperature. As an initial estimate, use the highest operating ambient temperature of interest and read $r_{DS(on)}$ from the typical characteristics graph. Using this value, the power dissipation can be calculated by:

$$P_D = (R_{DS(on)} \times I_{OUT1}^2) + (R_{DS(on)} \times I_{OUT2}^2)$$

Where:

P_D = Total power dissipation (W)

$r_{DS(on)}$ = Power switch on-resistance of one channel (Ω)

I_{OUTx} = Maximum current-limit threshold set by R_{ILIM} (A)

This step calculates the total power dissipation of the N-channel MOSFET.

Finally, calculate the junction temperature:

$$T_J = P_D \times \theta_{JA} + T_A$$

Where:

T_A = Ambient temperature ($^{\circ}$ C)

θ_{JA} = Thermal resistance ($^{\circ}$ C/W)

P_D = Total power dissipation (W)

Compare the calculated junction temperature with the initial estimate. If they are not within a few degrees, repeat the calculation using the "refined" $r_{DS(on)}$ from the previous calculation as the new estimate. Two or three iterations are generally sufficient to achieve the desired result. The final junction temperature is highly dependent on thermal resistance θ_{JA} , and thermal resistance is highly dependent on the individual package and board layout. The [Dissipating Rating Table](#) provides example thermal resistances for specific packages and board layouts.

AUTO-RETRY FUNCTIONALITY

Some applications require that an overcurrent condition disables the part momentarily during a fault condition and re-enables after a pre-set time. This auto-retry functionality can be implemented with an external resistor and capacitor. During a fault condition, $\overline{\text{FAULTx}}$ pulls ENx low disabling the part. The part is disabled when ENx is pulled below the turn-off threshold, and $\overline{\text{FAULTx}}$ goes high impedance allowing C_{RETRY} to begin charging. The part re-enables when the voltage on ENx reaches the turn-on threshold, and the auto-retry time is determined by the resistor/capacitor time constant. The part will continue to cycle in this manner until the fault condition is removed.

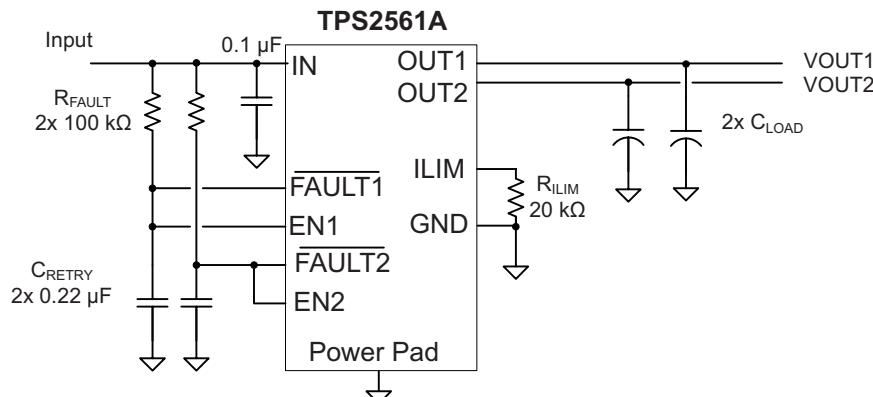


Figure 19. Auto-Retry Functionality

Some applications require auto-retry functionality and the ability to enable/disable with an external logic signal. The figure below shows how an external logic signal can drive EN through R_{FAULT} and maintain auto-retry functionality. The resistor/capacitor time constant determines the auto-retry time-out period.

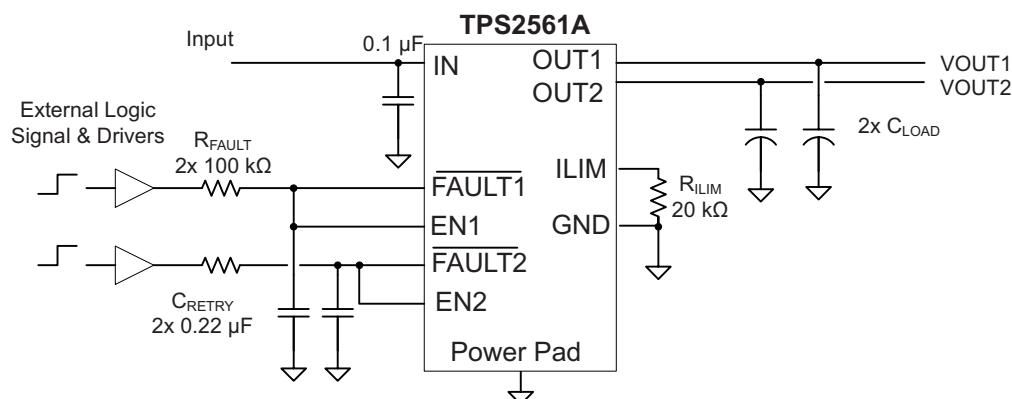


Figure 20. Auto-Retry Functionality With External EN Signal

TWO-LEVEL CURRENT-LIMIT CIRCUIT

Some applications require different current-limit thresholds depending on external system conditions. Figure 21 shows an implementation for an externally controlled, two-level current-limit circuit. The current-limit threshold is set by the total resistance from ILIM to GND (see previously discussed *Programming the Current-Limit Threshold* section). A logic-level input enables/disables MOSFET Q1 and changes the current-limit threshold by modifying the total resistance from ILIM to GND. Additional MOSFET/resistor combinations can be used in parallel to Q1/R2 to increase the number of additional current-limit levels.

NOTE

ILIM should never be driven directly with an external signal.

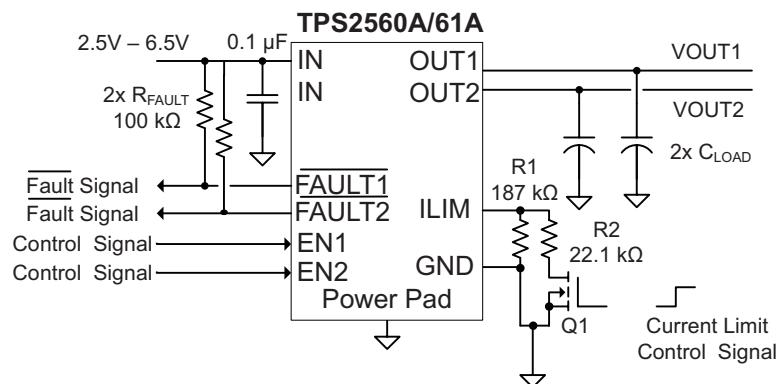


Figure 21. Two-Level Current-Limit Circuit

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
TPS2560ADRCR	PREVIEW	SON	DRC	10	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
TPS2560ADRCT	PREVIEW	SON	DRC	10	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
TPS2561ADRCR	PREVIEW	SON	DRC	10	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
TPS2561ADRCT	PREVIEW	SON	DRC	10	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

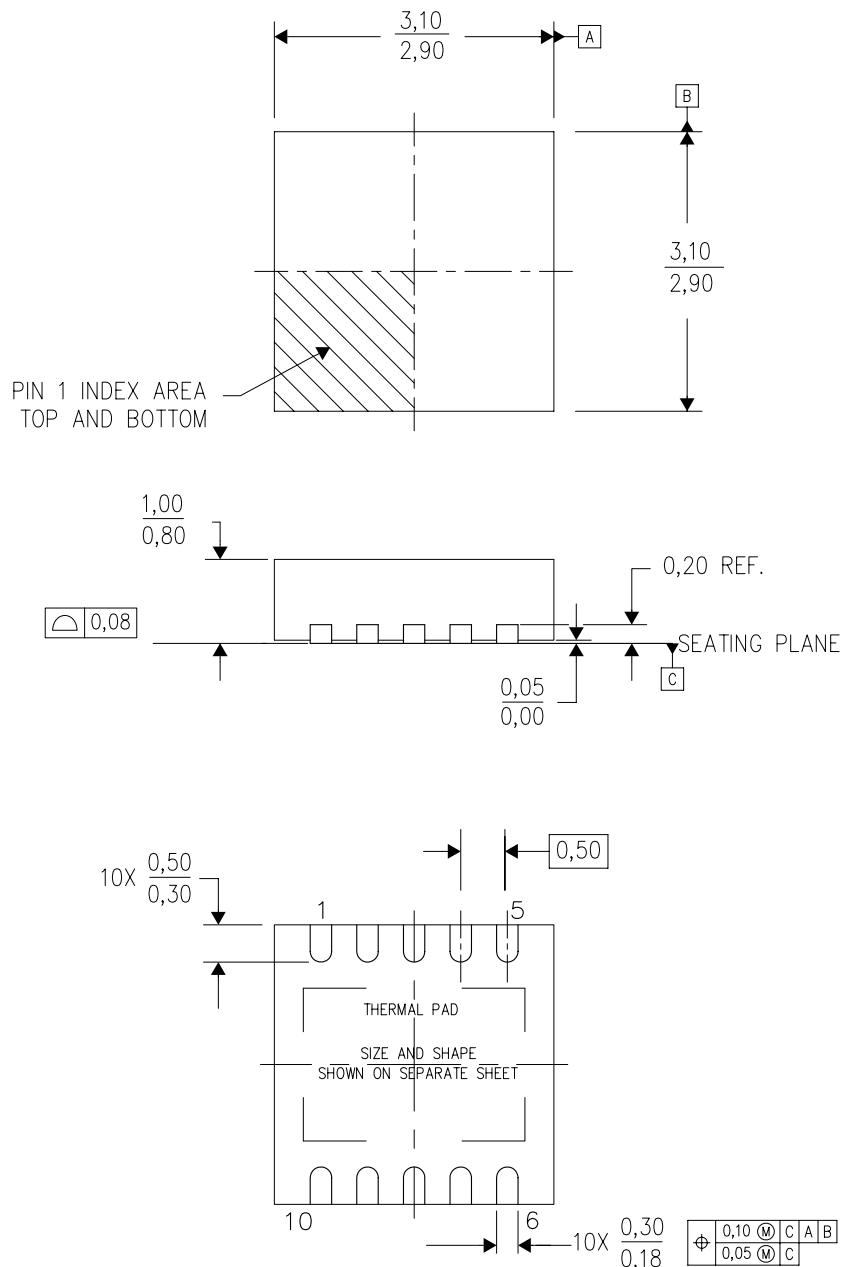
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MECHANICAL DATA

DRC (S-PVSON-N10)

PLASTIC SMALL OUTLINE NO-LEAD



4204102-3/L 09/11

NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.
C. Small Outline No-Lead (SON) package configuration.
D. The package thermal pad must be soldered to the board for thermal and mechanical performance, if present.
E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions, if present

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